

AN78Lxx/AN78LxxM Series

3-pin positive output voltage regulator (100 mA type)

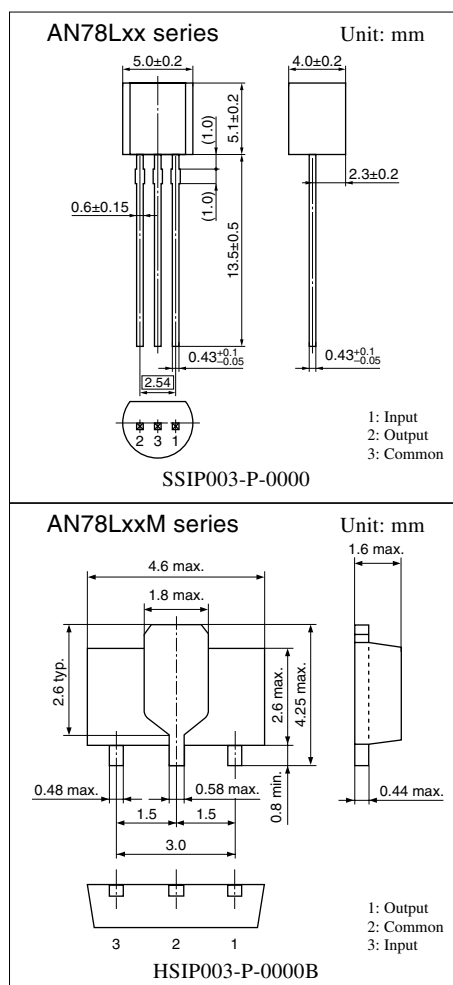
Overview

The AN78Lxx series and the AN78LxxM series are 3-pin fixed positive output type monolithic voltage regulator.

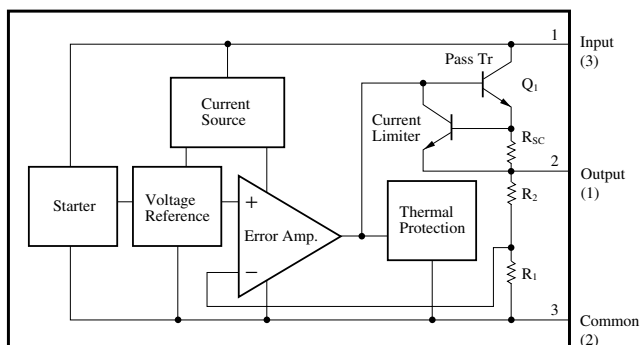
A stabilized fixed output voltage is obtained from an unstable DC input voltage without using any external parts. 12 types of fixed output voltage are available; 4V, 5V, 6V, 7V, 8V, 9V, 10V, 12V, 15V, 18V, 20V and 24V. They can be used widely as power circuits with a current capacity of up to 100mA.

Features

- No external components
- Output voltage: 4V, 5V, 6V, 7V, 8V, 9V, 10V, 12V, 15V, 18V, 20V, 24V
- Built-in overcurrent limit circuit
- Built-in thermal overload protection circuit



Block Diagram (AN78Lxx series)



Note) The number in () shows the pin number for the AN78LxxM series.

Note) The packages (SSIP003-P-0000 and HSIP003-P-0000B) of this product will be changed to lead-free type (SSIP003-P-0000S and HSIP003-P-0000Q). See the new package dimensions section later of this datasheet.

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter		Symbol	Rating	Unit
Input voltage		V _I	35 *1	V
			40 *2	V
Power dissipation		P _D	650 *3	mW
Operating ambient temperature		T _{opr}	−30 to +80	°C
Storage temperature	AN78Lxx series	T _{stg}	−55 to +150	°C
	AN78LxxM series		−55 to +125	

*1 AN78L04/M, AN78L05/M, AN78L06/M, AN78L07/M, AN78L08/M, AN78L09/M, AN78L10/M, AN78L12/M, AN78L15/M

*2 AN78L18/M, AN78L20/M, AN78L24/M

*3 Follow the derating curve. When T_j exceeds 150°C , the internal circuit cuts off the output.

AN78LxxM series is mounted on a standard board (glass epoxy: 20mm × 20mm × t1.7mm with Cu foil of 1cm² or more).

Electrical Characteristics at $T_a = 25^\circ\text{C}$

• AN78L04, AN78L04M (4V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	3.84	4	4.16	V
Output voltage tolerance	V_O	$V_i = 6.5$ to 19V, $I_O = 1$ to 70mA	3.8	—	4.2	V
Line regulation	REG_{IN}	$V_i = 6.5$ to 19V, $T_j = 25^\circ\text{C}$	—	50	145	mV
		$V_i = 7$ to 19V, $T_j = 25^\circ\text{C}$	—	40	95	mV
Load regulation	REG_L	$I_O = 1$ to 100mA, $T_j = 25^\circ\text{C}$	—	10	55	mV
		$I_O = 1$ to 40mA, $T_j = 25^\circ\text{C}$	—	4.5	30	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_i = 7$ to 19V, $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_O = 1$ to 40mA, $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	40	—	μV
Ripple rejection ratio	RR	$V_i = 7$ to 17V, $I_O = 40\text{mA}$, $f = 120\text{Hz}$	48	58	—	dB
Minimum input/output voltage difference	$V_{DIF(min)}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{O(Short)}$	$T_j = 25^\circ\text{C}$, $V_i = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-0.6	—	mV/ $^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_i = 9\text{V}$, $I_O = 40\text{mA}$, $C_1 = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L04) and $T_j = 0$ to 100°C (AN78L04M)

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN78L05, AN78L05M (5V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	4.8	5	5.2	V
Output voltage tolerance	V_O	$V_I = 7.5$ to 20V , $I_O = 1$ to 70mA	4.75	—	5.25	V
Line regulation	REG_{IN}	$V_I = 7.5$ to 20V , $T_j = 25^\circ\text{C}$	—	55	150	mV
		$V_I = 8$ to 20V , $T_j = 25^\circ\text{C}$	—	45	100	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	11	60	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	5	30	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 8$ to 20V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	40	—	μV
Ripple rejection ratio	RR	$V_I = 8$ to 18V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	47	57	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-0.65	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 10\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L05) and $T_j = 0$ to 100°C (AN78L05M)

• AN78L06, AN78L06M (6V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	5.76	6	6.24	V
Output voltage tolerance	V_O	$V_I = 8.5$ to 21V , $I_O = 1$ to 70mA	5.7	—	6.3	V
Line regulation	REG_{IN}	$V_I = 8.5$ to 21V , $T_j = 25^\circ\text{C}$	—	60	155	mV
		$V_I = 9$ to 21V , $T_j = 25^\circ\text{C}$	—	50	105	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	12	65	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	5.5	35	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 9$ to 21V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	50	—	μV
Ripple rejection ratio	RR	$V_I = 9$ to 19V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	46	56	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-0.7	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 11\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L06) and $T_j = 0$ to 100°C (AN78L06M)

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN78L07, AN78L07M (7V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	6.72	7	7.28	V
Output voltage tolerance	V_O	$V_I = 9.5$ to 22V , $I_O = 1$ to 70mA	6.65	—	7.35	V
Line regulation	REG_{IN}	$V_I = 9.5$ to 22V , $T_j = 25^\circ\text{C}$	—	70	165	mV
		$V_I = 10$ to 22V , $T_j = 25^\circ\text{C}$	—	60	115	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	13	75	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	6	35	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 10$ to 22V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	50	—	μV
Ripple rejection ratio	RR	$V_I = 10$ to 20V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	45	55	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-0.75	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 12\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L07) and $T_j = 0$ to 100°C (AN78L07M)

• AN78L08, AN78L08M (8V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	7.7	8	8.3	V
Output voltage tolerance	V_O	$V_I = 10.5$ to 23V , $I_O = 1$ to 70mA	7.6	—	8.4	V
Line regulation	REG_{IN}	$V_I = 10.5$ to 23V , $T_j = 25^\circ\text{C}$	—	80	175	mV
		$V_I = 11$ to 23V , $T_j = 25^\circ\text{C}$	—	70	125	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	15	80	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	7	40	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 11$ to 23V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	60	—	μV
Ripple rejection ratio	RR	$V_I = 11$ to 21V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	44	54	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-0.8	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 14\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L08) and $T_j = 0$ to 100°C (AN78L08M)

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN78L09, AN78L09M (9V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	8.64	9	9.35	V
Output voltage tolerance	V_O	$V_I = 11.5$ to 24V , $I_O = 1$ to 70mA	8.55	—	9.45	V
Line regulation	REG_{IN}	$V_I = 11.5$ to 24V , $T_j = 25^\circ\text{C}$	—	90	190	mV
		$V_I = 12$ to 24V , $T_j = 25^\circ\text{C}$	—	80	140	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	16	85	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	8	45	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 12$ to 24V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	65	—	μV
Ripple rejection ratio	RR	$V_I = 12$ to 22V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	43	53	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-0.85	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 15\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L09) and $T_j = 0$ to 100°C (AN78L09M)

• AN78L10, AN78L10M (10V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	9.6	10	10.4	V
Output voltage tolerance	V_O	$V_I = 12.5$ to 25V , $I_O = 1$ to 70mA	9.5	—	10.5	V
Line regulation	REG_{IN}	$V_I = 12.5$ to 25V , $T_j = 25^\circ\text{C}$	—	100	210	mV
		$V_I = 13$ to 25V , $T_j = 25^\circ\text{C}$	—	90	160	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	17	90	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	9	45	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 13$ to 25V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	70	—	μV
Ripple rejection ratio	RR	$V_I = 13$ to 23V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	42	52	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-0.9	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 16\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L10) and $T_j = 0$ to 100°C (AN78L10M)

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN78L12, AN78L12M (12V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	11.5	12	12.5	V
Output voltage tolerance	V_O	$V_I = 14.5$ to 27V , $I_O = 1$ to 70mA	11.4	—	12.6	V
Line regulation	REG_{IN}	$V_I = 14.5$ to 27V , $T_j = 25^\circ\text{C}$	—	120	250	mV
		$V_I = 15$ to 27V , $T_j = 25^\circ\text{C}$	—	100	200	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	20	100	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	10	50	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3.5	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 15$ to 27V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	80	—	μV
Ripple rejection ratio	RR	$V_I = 15$ to 25V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	40	50	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	−1	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 19\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L12) and $T_j = 0$ to 100°C (AN78L12M)

• AN78L15, AN78L15M (15V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	14.4	15	15.6	V
Output voltage tolerance	V_O	$V_I = 17.5$ to 30V , $I_O = 1$ to 70mA	14.25	—	15.75	V
Line regulation	REG_{IN}	$V_I = 17.5$ to 30V , $T_j = 25^\circ\text{C}$	—	130	300	mV
		$V_I = 18$ to 30V , $T_j = 25^\circ\text{C}$	—	110	250	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	25	150	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	12	75	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3.5	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 18$ to 30V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	90	—	μV
Ripple rejection ratio	RR	$V_I = 18$ to 28V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	38	48	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	−1.3	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 23\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L15) and $T_j = 0$ to 100°C (AN78L15M)

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

• AN78L18, AN78L18M (18V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	17.3	18	18.7	V
Output voltage tolerance	V_O	$V_I = 20.5$ to 33V , $I_O = 1$ to 70mA	17.1	—	18.9	V
Line regulation	REG_{IN}	$V_I = 20.5$ to 33V , $T_j = 25^\circ\text{C}$	—	45	300	mV
		$V_I = 21$ to 33V , $T_j = 25^\circ\text{C}$	—	35	250	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	30	170	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	15	85	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3.5	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 21$ to 33V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	150	—	μV
Ripple rejection ratio	RR	$V_I = 21$ to 31V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	36	46	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-1.5	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 27\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L18) and $T_j = 0$ to 100°C (AN78L18M)

• AN78L20, AN78L20M (20V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	19.2	20	20.8	V
Output voltage tolerance	V_O	$V_I = 22.5$ to 35V , $I_O = 1$ to 70mA	19	—	21	V
Line regulation	REG_{IN}	$V_I = 22.5$ to 35V , $T_j = 25^\circ\text{C}$	—	50	300	mV
		$V_I = 23$ to 35V , $T_j = 25^\circ\text{C}$	—	40	250	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	35	180	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	17	90	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3.5	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 23$ to 35V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	170	—	μV
Ripple rejection ratio	RR	$V_I = 23$ to 33V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	34	44	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-1.7	—	$\text{mV}/^\circ\text{C}$

Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 29\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L20) and $T_j = 0$ to 100°C (AN78L20M)

■ Electrical Characteristics at $T_a = 25^\circ\text{C}$ (continued)

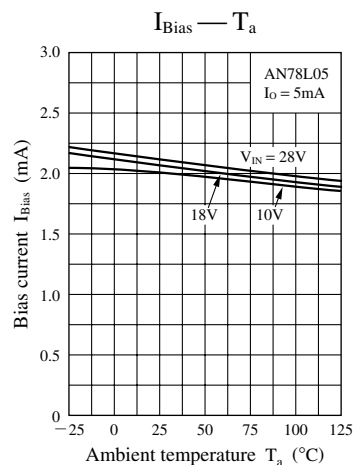
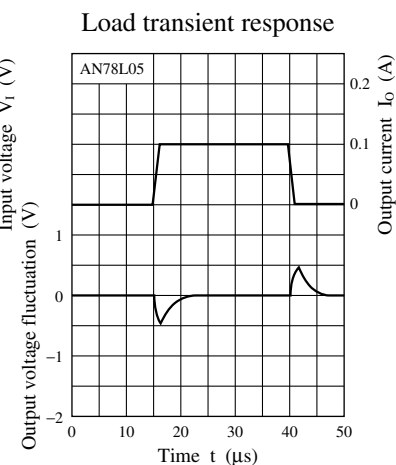
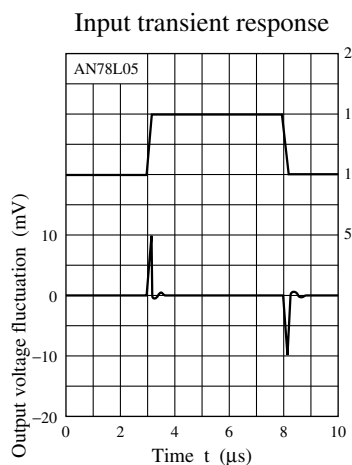
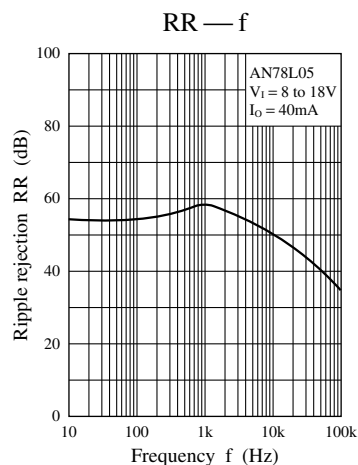
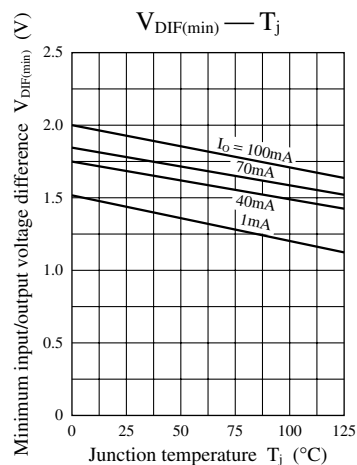
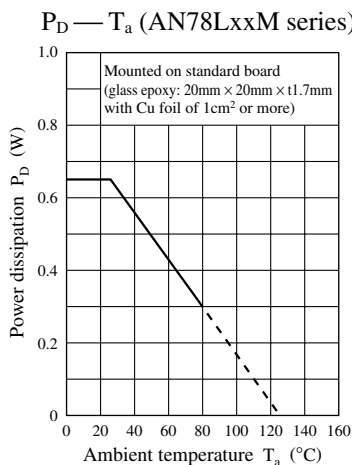
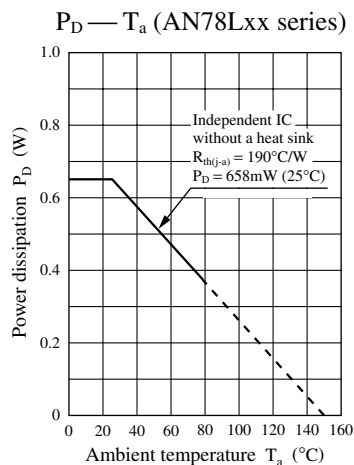
• AN78L24, AN78L24M (24V type)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Output voltage	V_O	$T_j = 25^\circ\text{C}$	23	24	25	V
Output voltage tolerance	V_O	$V_I = 26.5$ to 39V , $I_O = 1$ to 70mA	22.8	—	25.2	V
Line regulation	REG_{IN}	$V_I = 26.5$ to 39V , $T_j = 25^\circ\text{C}$	—	60	300	mV
		$V_I = 27$ to 39V , $T_j = 25^\circ\text{C}$	—	50	250	mV
Load regulation	REG_L	$I_O = 1$ to 100mA , $T_j = 25^\circ\text{C}$	—	40	200	mV
		$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	20	100	mV
Bias current	I_{Bias}	$T_j = 25^\circ\text{C}$	—	2	3.5	mA
Bias current fluctuation to input	$\Delta I_{\text{Bias(IN)}}$	$V_I = 27$ to 39V , $T_j = 25^\circ\text{C}$	—	—	1	mA
Bias current fluctuation to load	$\Delta I_{\text{Bias(L)}}$	$I_O = 1$ to 40mA , $T_j = 25^\circ\text{C}$	—	—	0.1	mA
Output noise voltage	V_{no}	$f = 10\text{Hz}$ to 100kHz	—	200	—	μV
Ripple rejection ratio	RR	$V_I = 27$ to 37V , $I_O = 40\text{mA}$, $f = 120\text{Hz}$	34	44	—	dB
Minimum input/output voltage difference	$V_{\text{DIF(min)}}$	$T_j = 25^\circ\text{C}$	—	1.7	—	V
Output short-circuit current	$I_{\text{O(Short)}}$	$T_j = 25^\circ\text{C}$, $V_I = 35\text{V}$	—	140	—	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_O = 5\text{mA}$, $T_j = 0$ to 125°C	—	-2	—	$\text{mV}/^\circ\text{C}$

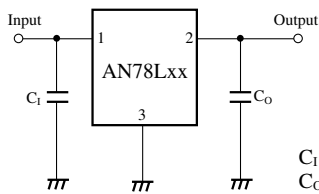
Note 1) The specified condition $T_j = 25^\circ\text{C}$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 33\text{V}$, $I_O = 40\text{mA}$, $C_I = 0.33\mu\text{F}$, $C_O = 0.1\mu\text{F}$, $T_j = 0$ to 125°C (AN78L24) and $T_j = 0$ to 100°C (AN78L24M)

■ Main Characteristics



Basic Regulator Circuit



C_1 is necessary when the input line is long.
 C_0 improves the transient response.

Usage Notes

1. Cautions for a basic circuit

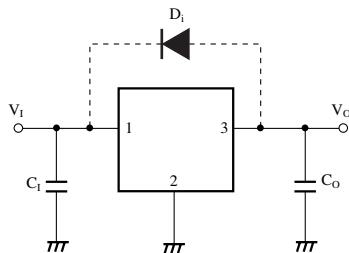


Figure 1

C_1 : When a wiring from a smoothing circuit to a three-pin regulator is long, it is likely to oscillate at output. A capacitor of $0.1\mu\text{F}$ to $0.47\mu\text{F}$ should be connected near an input pin.

C_0 : When any sudden change of load current is likely to occur, connect an electrolytic capacitor of $10\mu\text{F}$ to $100\mu\text{F}$ to improve a transitional response of output voltage.

D_1 : Normally unnecessary. But add it in the case that there is a residual voltage at the output capacitor C_0 even after switching off the supply power because a current is likely to flow into an output pin of the IC and damage the IC.

2. Other caution items

1) Short-circuit between the input pin and GND pin

If the input pin is short-circuited to GND or is cut off when a large capacitance capacitor has been connected to the IC's load, a voltage of a capacitor connected to an output pin is applied between input/output of the IC and this likely results in damage of the IC. It is necessary, therefore, to connect a diode, as shown in figure 2, to counter the reverse bias between input/output pins.

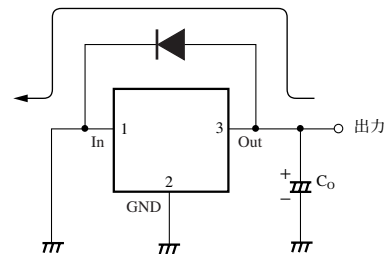
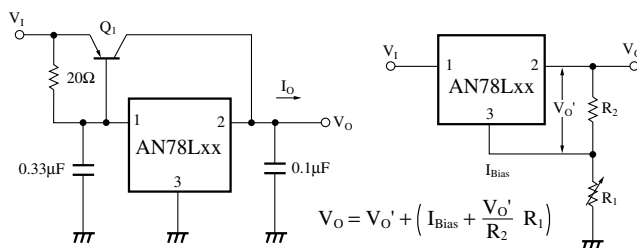


Figure 2

2) Floating of GND pin

If a GND pin is made floating in an operating mode, an unstabilized input voltage is outputted. In this case, a thermal protection circuit inside the IC does not normally operate. In this state, if the load is short-circuited or overloaded, it is likely to damage the IC.

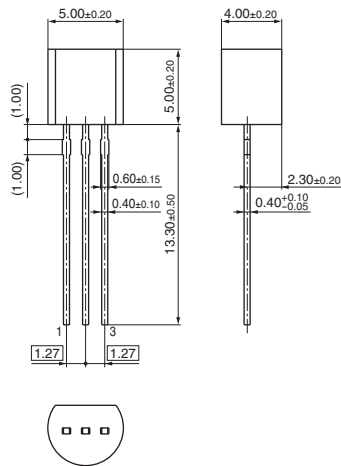
Application Circuit Examples



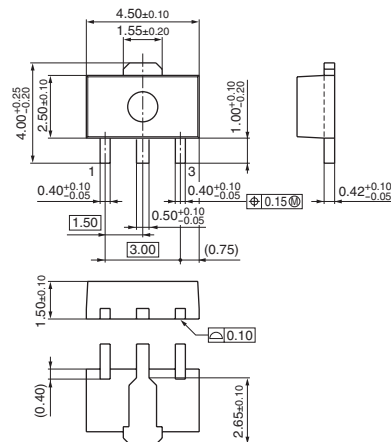
Note) V_O varies due to sample to sample variation of I_{Bias} .
 Never fail to adjust individually with R_1 .

■ New Package Dimensions (Unit: mm)

- SSIP003-P-0000S (Lead-free package)



- HSIP003-P-0000Q (Lead-free package)



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